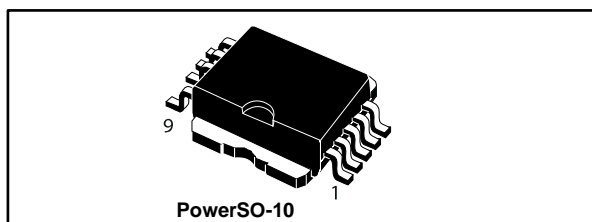


Quad high-side smart power solid-state relay

Datasheet - production data



- Open drain diagnostic output
- Fast demagnetization of inductive loads
- Conforms to IEC 61131-2

Description

The VN340SP-33-E is a monolithic device developed using STMicroelectronics' VIPower technology, intended to drive four independent resistive or inductive loads with one side connected to ground. Active current limitation prevents dropping of the system power supply in case of shorted load. Built-in thermal shutdown protects the chip from overtemperature and short-circuit. The open drain diagnostic output indicates overtemperature conditions. Each I/O is pulled down when the overtemperature condition of the relative channel is verified.

Features

Type	$V_{\text{demag}}^{(1)}$	$R_{\text{DS(on)}}^{(1)}$	$I_{\text{OUT}}^{(1)}$	V_{CC}
VN340SP-33-E	$V_{\text{CC}}-55\text{ V}$	$0.2\ \Omega$	1 A	36 V

Notes:

⁽¹⁾Per channel

- Output current: 1 A per channel
- Digital I/O clamped at 32 V minimum voltage
- Shorted load and overtemperature protections
- Protection against loss of ground
- Built-in current limiter
- Undervoltage shutdown

Table 1: Device summary

Order code	Package	Packing
VN340SP-33-E	PowerSO-10	Tube
VN340SPTR-33-E		Tape and reel

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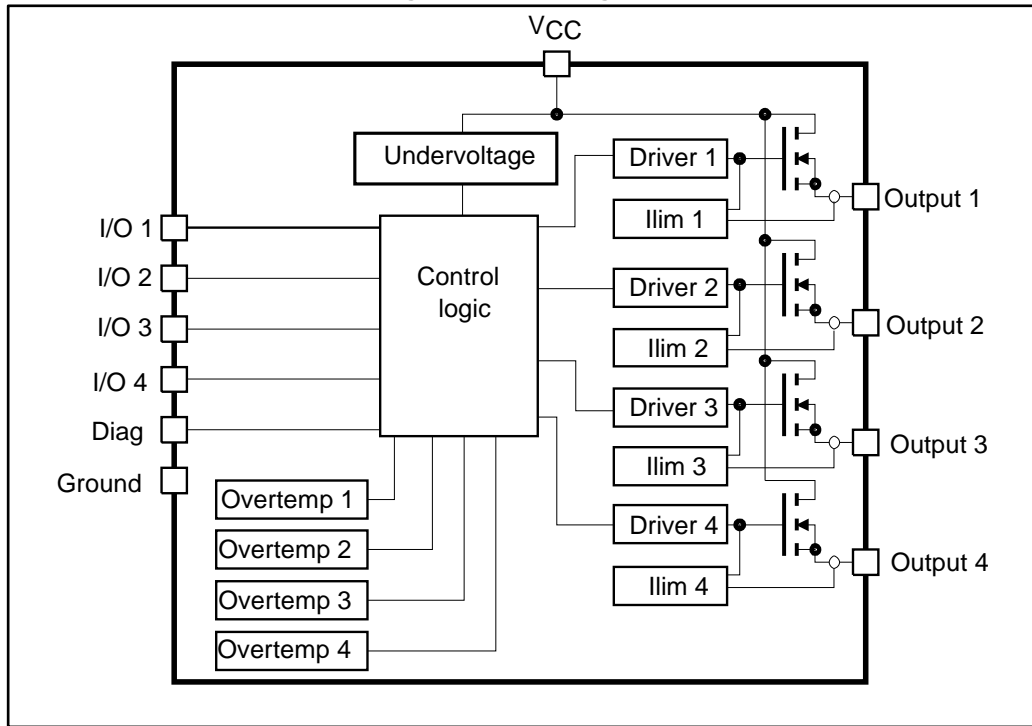
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1 Block diagram

Figure 1: Block diagram



2 Pin connection

Figure 2: Connection diagram (top view)

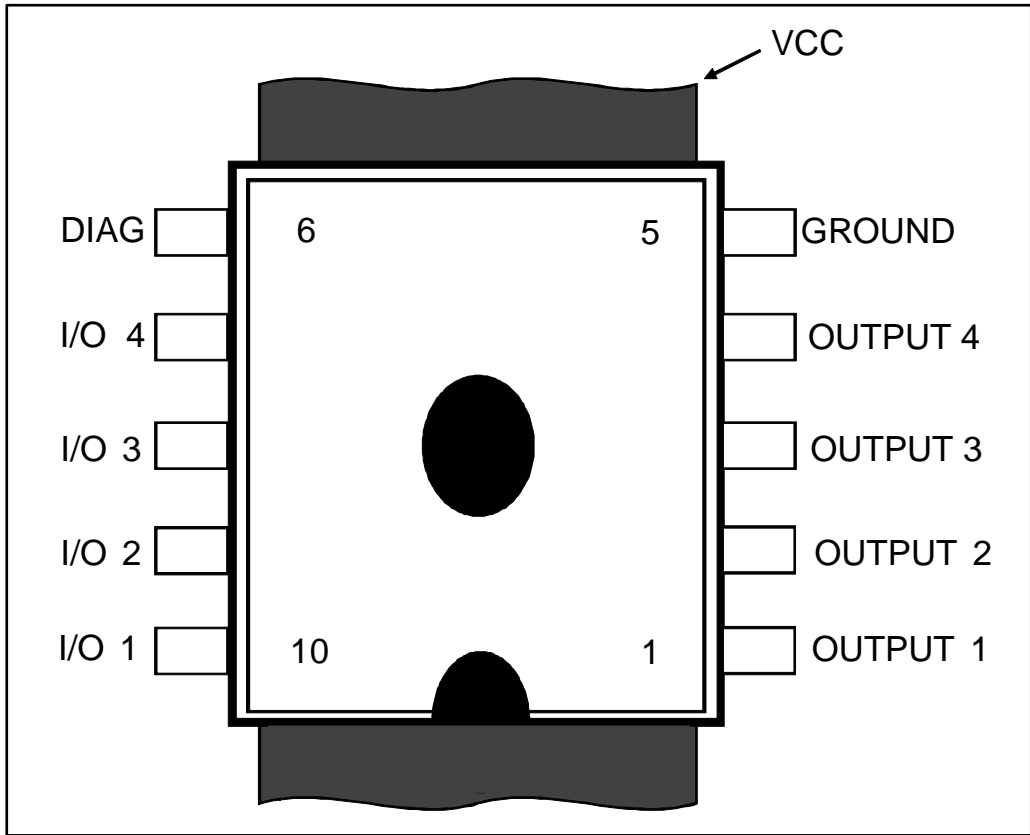
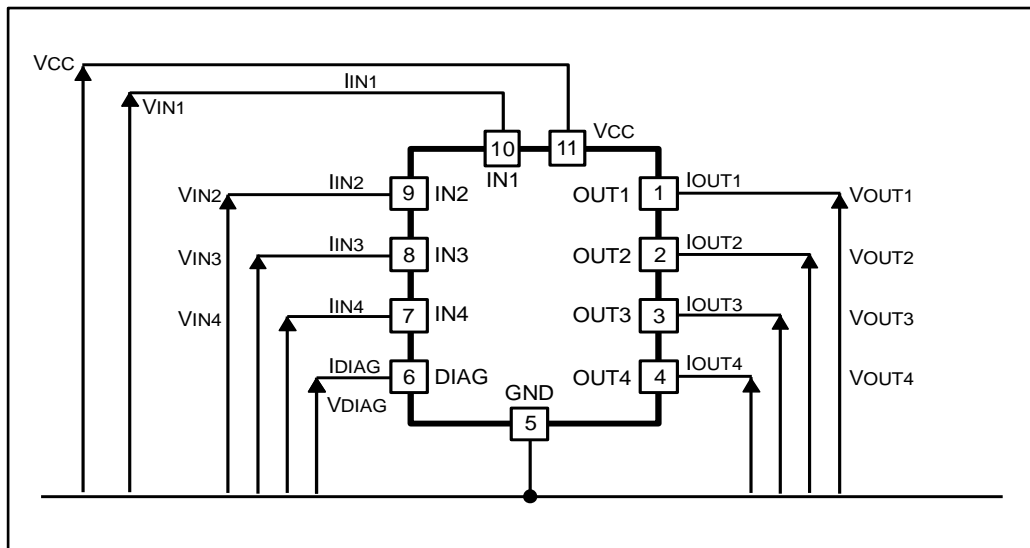


Figure 3: Current and voltage conventions



3 Maximum ratings

Table 2: Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Power supply voltage	45	V
$-V_{CC}$	Reverse supply voltage	-4	V
I_{OUT}	Output current	Internally limited	A
I_R	Reverse output current (per channel)	-6	A
I_{IN}	Input current range	-1 to +10	mA
I_{DIAG}	Diag pin current	-1 to +10	mA
V_{ESD}	Electrostatic discharge (R = 1.5 k Ω ; C = 100 pF)	2000	V
E_{AS}	Single pulse avalanche energy one channel active $T_J = 125^\circ$, $I_{LOAD} = 0.625$ A	10	J
	Single pulse avalanche energy all channel active simultaneously $T_J = 125^\circ$, $I_{LOAD} = 0.625$ A	2	J
P_{TOT}	Power dissipation at $T_C = 25^\circ\text{C}$	Internally limited	W
T_J	Junction operating temperature	Internally limited	$^\circ\text{C}$
T_{STG}	Storage temperature	-55 to 150	$^\circ\text{C}$

Table 3: Thermal data

Symbol	Parameter	Value	Unit
$R_{th(JC)}$	Thermal resistance junction-case ⁽¹⁾	Max. 3	$^\circ\text{C/W}$
$R_{th(JA)}$	Thermal resistance junction-ambient ⁽²⁾	Max. 50	$^\circ\text{C/W}$

Notes:

⁽¹⁾Per channel.

⁽²⁾When mounted on a four-layer FR4, with the minimum recommended pad size.

4 Electrical characteristics

10 V < V_{CC} < 36 V; -40 °C < T_J < 125 °C; unless otherwise specified

Table 4: Power section

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V _{CC}	Supply voltage		10		36	V
R _{DS(on)}	On-state resistance	I _{OUT} = 0.5 A at T _J = 25 °C			0.2	Ω
		I _{OUT} = 0.5 A at T _J = 85 °C			0.32	
		I _{OUT} = 0.5 A at T _J = 125 °C			0.4	
I _S	Supply current	All channels in OFF-state, V _{IN} = 30 V, I _{OUT} = 0 V, T _J = 125 °C			1	mA
					6	mA
V _{OL}	Low state output voltage	V _{IN} = V _{IL} ; R _{LOAD} > = 10 MΩ			1.5	μA
I _{LGND}	Output current at turn-off	V _{CC} = V _{IN} = V _{GND} = V _{STAT} = 18 to 30 V T _A = -25 °C to 85 °C			2	mA
V _{demag}	Output current at turn-off	I _{OUT} = 0.5 A; L _{LOAD} > = 1 mH	V _{CC} -65	V _{CC} -55	V _{CC} -45	V

Table 5: Switching (V_{CC} = 24 V, T_J = 25 °C)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
t _{d(ON)}	Turn-on delay time	I _{OUT} = 0.5 A, resistive load, input rise time < 0.1 μs		52	100	μs
t _r	Rise time of output current	I _{OUT} = 0.5 A, resistive load, input rise time < 0.1 μs		94	250	μs
t _{d(OFF)}	Turn-off delay time of output current	I _{OUT} = 0.5 A, resistive load, input rise time < 0.1 μs		34	50	μs
t _f	Fall time	I _{OUT} = 0.5 A, resistive load, input rise time < 0.1 μs		8	20	μs

Table 6: Logic inputs

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{IL}	I/O input low level voltage				2	V
V_{IH}	I/O input high level voltage		3.5			V
$V_{I(HYST)}$	I/O input hysteresis voltage			0.5		V
I_{IN}	I/O input current	$V_{IN} = 30\text{ V}$			25	μA
V_{ICL}	I/O input clamp voltage ⁽¹⁾	$I_{IN} = 1\text{ mA}$	32	36		V
		$I_{IN} = -1\text{ mA}$		-0.7		V

Notes:

⁽¹⁾The input voltage is internally clamped at 32 V minimum, the input pins can be connected to a higher voltage by an external resistor, which cannot exceed 10 mA

Table 7: Protection and diagnostic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{DIAG}^{(1)}$	Status voltage output low	$I_{DIAG} = 5\text{ mA}$ (fault condition)			1	V
V_{SCL}	Status clamp voltage	$I_{DIAG} = 1\text{ mA}$	32	36 -0.7		
V_{USD}	Undervoltage shutdown		5		8	V
I_{lim}	DC short-circuit current	$V_{CC} = 24\text{ V}; R_{LOAD} < 10\text{ m}\Omega$	1		2	A
I_{OVPK}	Peak short-circuit current	$V_{CC} = 24\text{ V}; V_{IN} = 30\text{ V}; R_{LOAD} < 10\text{ m}\Omega$			4	V
I_{DIAGH}	Leakage on DIAG pin in high state	$V_{DIAG} = 24\text{ V}$			25	μA
I_{LOAD}	Output leakage current	$V_{CC} = 10\text{ to }36\text{ V}; V_{IN} = V_{IL}$			50	μA
t_{SC}	Delay time of current limiter				100	μs
T_{TSD}	Junction shutdown temperature		150	170		$^{\circ}\text{C}$
T_R	Junction reset temperature		135	155		$^{\circ}\text{C}$

Notes:

⁽¹⁾Status determination > 100 μs after the switching edge.



If the INPUT pin is left floating, the corresponding channel automatically switches off. If GND pin is disconnected, the channel switches off provided that V_{CC} does not exceed 36 V.

5 Test circuits

Figure 4: Avalanche energy test circuit

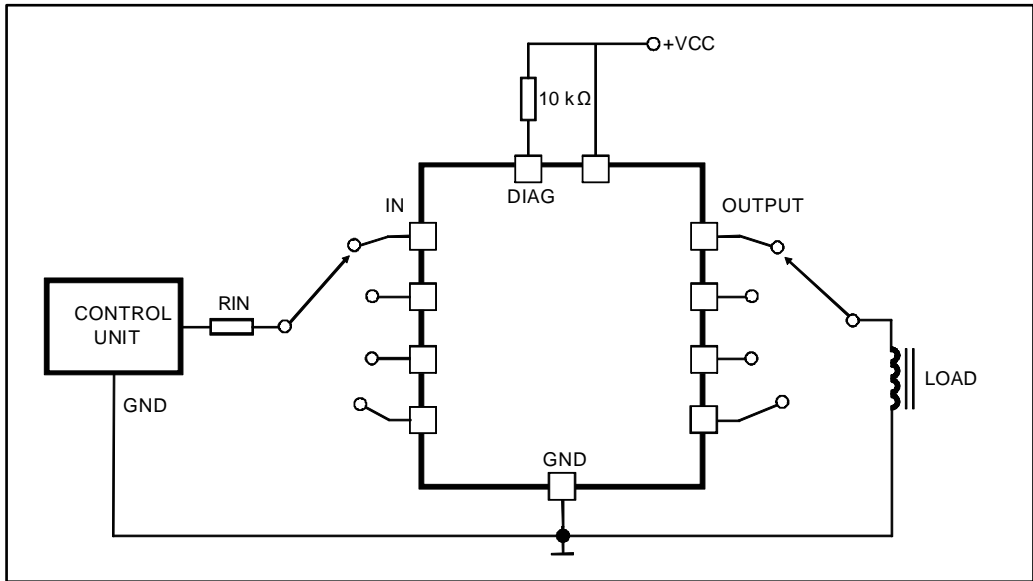


Figure 5: Peak short-circuit test diagram

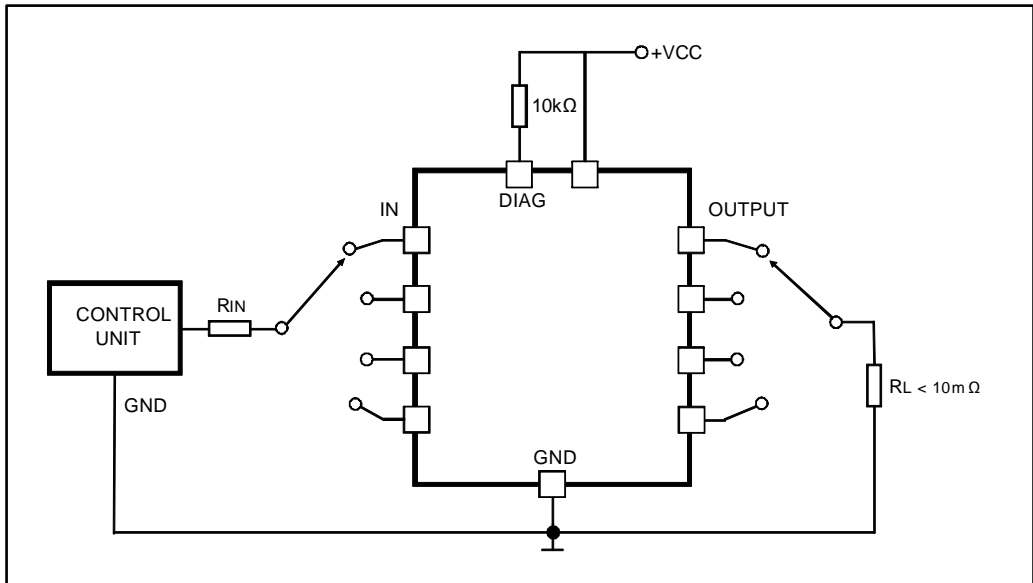
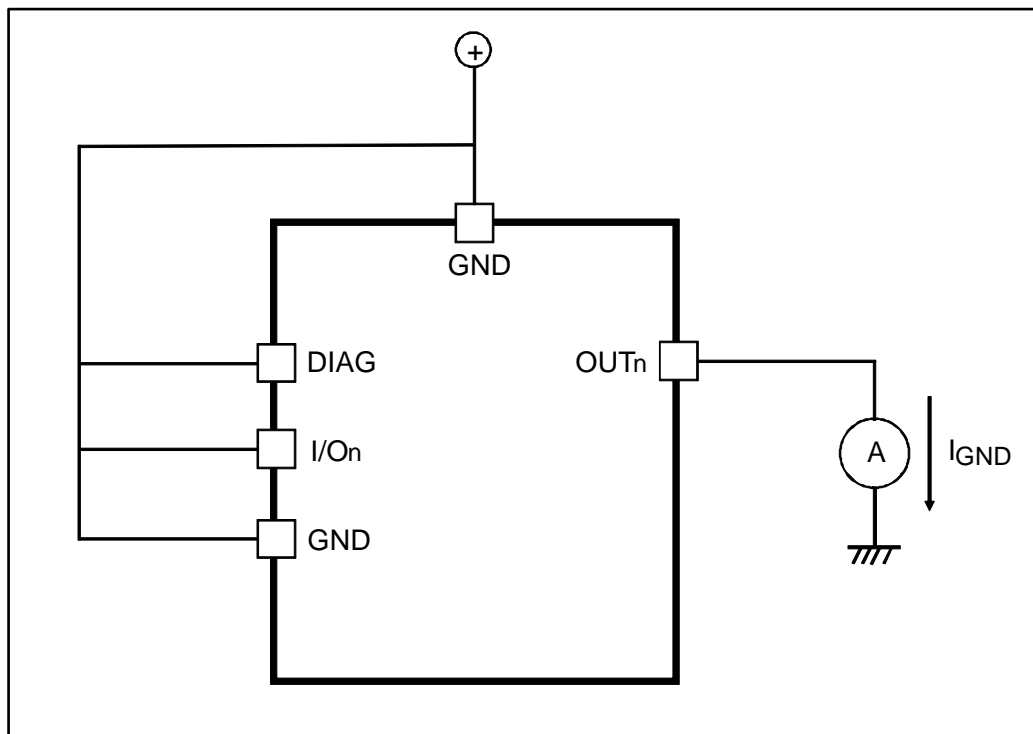


Figure 6: I_{LGND} test configuration



6 Switching time waveforms and truth table

Figure 7: Switching waveforms

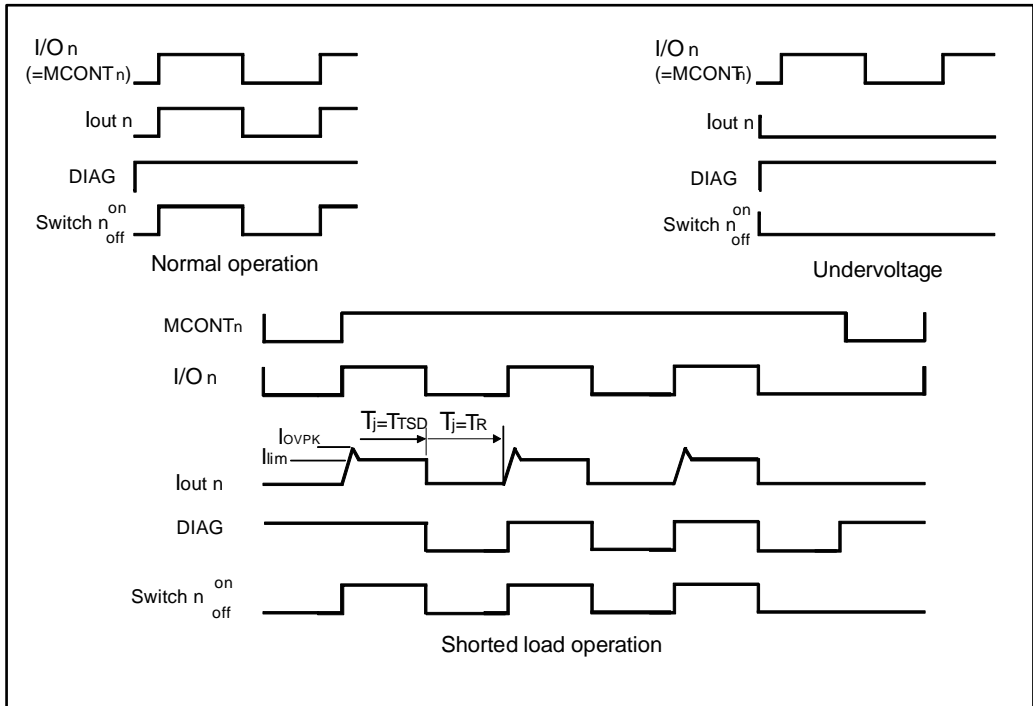


Figure 8: Switching parameter test conditions

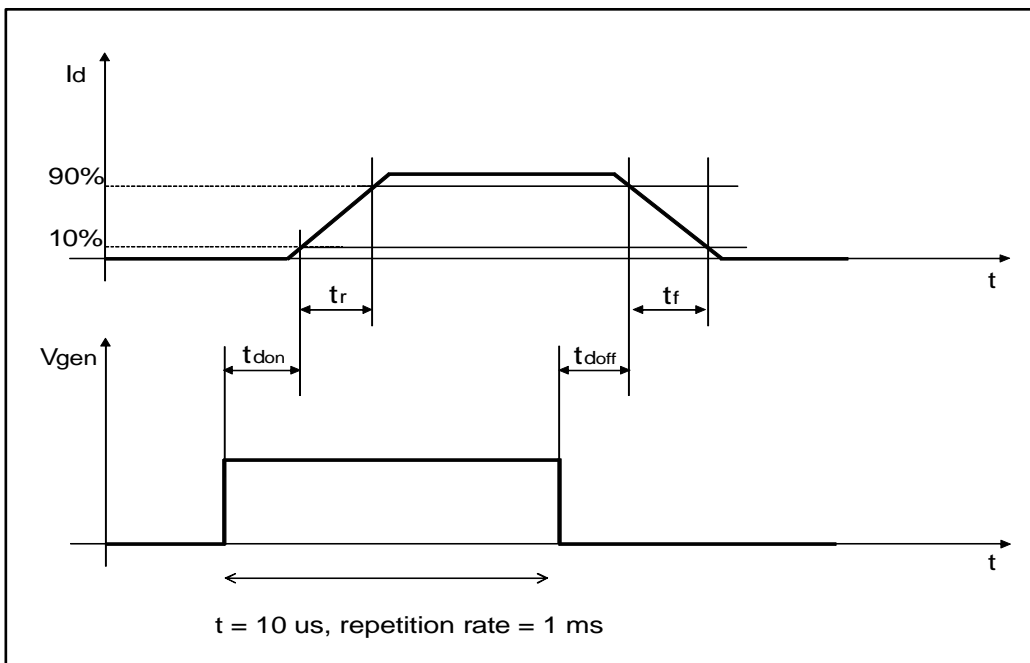


Table 8: Truth table

Conditions	MCOUTn	I/O n	OUTPUTn	Diagnostic
Normal operation	L	L	L	H
	H	H	H	H
Junction overtemperature	L	L	L	H
	H	L	L	L
Undervoltage	L	L	L	H
	H	H	L	H
Shorted load current limitation	L	L	L	H
	H	H	H	H

Figure 9: Driving circuit

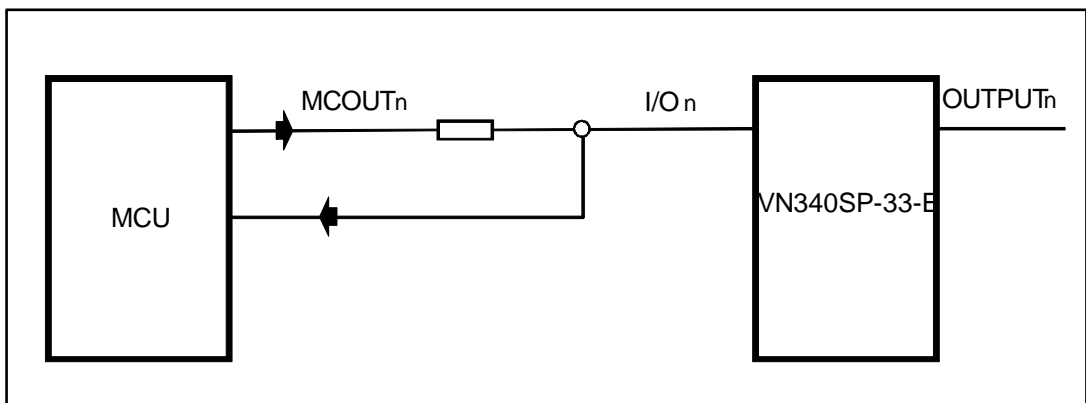


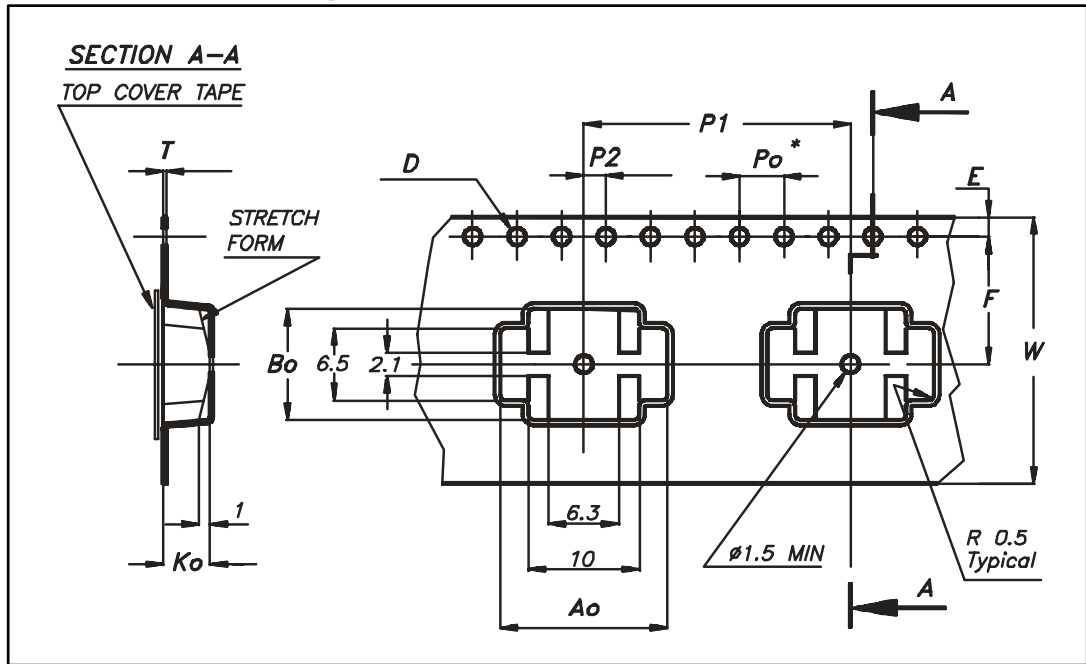
Table 9: PowerSO-10 package mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A1	0.01	0.05	0.08
A2	3.45	3.5	3.55
A3	1.24	1.28	1.32
A4	0.15	0.2	0.25
a		0.2	
b	0.4	0.45	0.5
c	0.24	0.27	0.3
D	9.45	9.52	9.59
D1	7.42	7.5	7.58
d	0	0.04	0.09
E	13.9	14.1	14.3
E1 ^a	9.33	9.4	9.47
E2	7.4	7.42	7.5
E3	5.95	6.1	6.25
e	1.22	1.27	1.32
e1		5.08	
F		0.5	
G		1.2	
L	0.85	1	1.1
R1			0.25
R2		0.8	
T	3 deg	5 deg	7 deg
T1		6 deg	
T2		10deg	

^a Resin protrusions are not included (max. value: 0.15 mm per side).

7.2 PowerSO-10 packing information

Figure 11: PowerSO-10 career tape outline



Drawing is not in scale

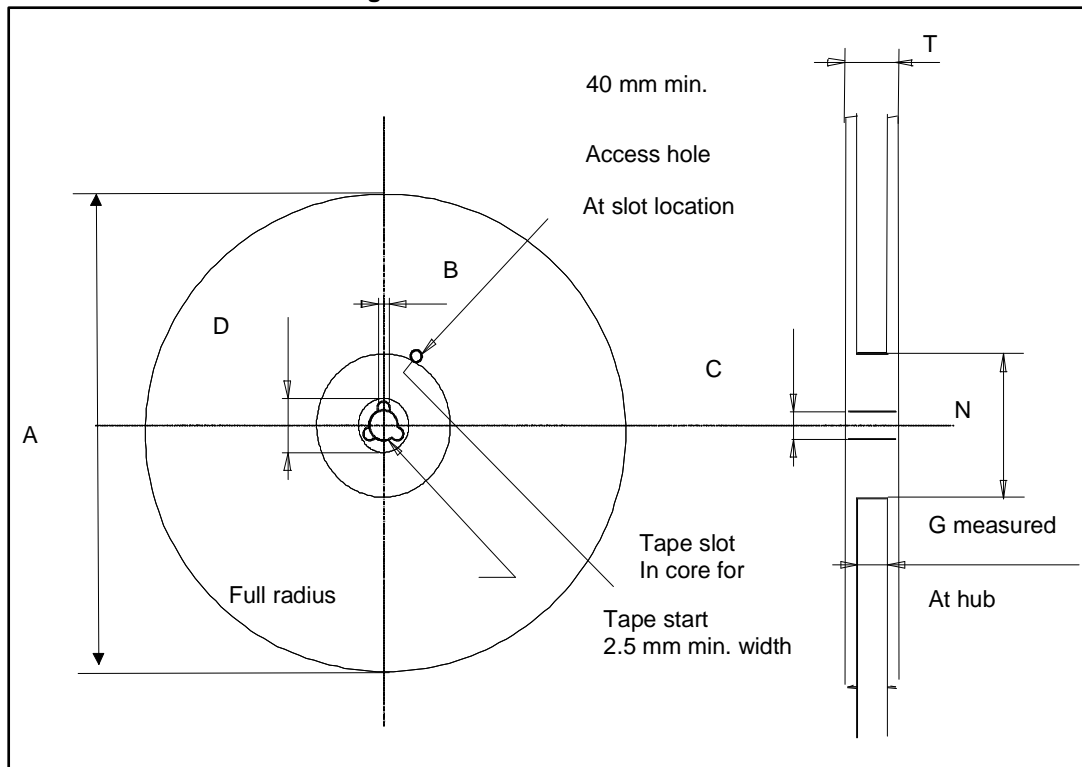
Table 10: PowerSO-10 career tape dimension mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A0	14.9	15.0	15.1
B0	9.9	10.0	10.1
K0	4.15	4.25	4.35
F	11.4	11.5	11.6
E	1.65	1.75	1.85
W	23.7	24.0	24.3
P2	1.9	2.0	2.1
P0	3.9	4.0	4.1
P1	23.9	24.0	24.1
T	0.025	0.30	0.35
D(Ø)	1.50	1.55	1.60



10 sprocket hole pitch cumulative tolerance ± 0.2 mm

Figure 12: PowerSO-10 reel outline



Drawing is not in scale

Table 11: PowerSO-10 reel dimension mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A			330
B	1.5		
C	12.8	13	13.2
D	20.2		
N	60		
G	23.7	24.4	
T			30.4



10 sprocket hole pitch cumulative tolerance ± 0.2 mm

Table 12: PowerSO-10 base and bulk quantity

Base quantity	Bulk quantity
600	600

8 Revision history

Table 13: Document revision history

Date	Revision	Changes
05-Sep-2005	1	Initial release.
19-Mar-2007	2	Document reformatted, typo in note 1.
22-Aug-2008	3	Updated table 9.
07-Sep-2015	4	Updated the table of absolute maximum ratings.

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